

# Monolithic JFET-Input Operational Amplifiers

## PM-155A/PM-156A/PM-157A

#### **FEATURES**

#### **All Devices**

~	THE CONTRACT OF THE CONTRACT O	
	Low Input Blas and Offset Currents	
	Low Input Offset Voltage	1.0mV
	Low Input Offset Voltage Drift	
•	Low Input Noise Current	. 0.01pA/√Hz
	High Common-Mode Rejection Ratio	
	PM-155 (Only) LF19	55 Replacement
•	Low Supply Current	
	PM-156 (Only) LF19	56 Replacement
•	High Siew Rate	
	Fast Settling to ±0.01%	
	PM-157 (Only) LF19	57 Replacement
•	Wide-Bandwidth Decompensated (A <sub>VCL</sub> =	
•		

#### **GENERAL DESCRIPTION**

The PM JFET-input series provides low input current, high slew rate, and direct interchangeability with LF155, 156, and 157 types. These operational amplifiers use a new process which allows fabrication of matched JFET transistors and standard bipolar transistors on the same chip. High accuracy and low cost make the PM JFET-input series useful in new designs and as replacements for modular and hybrid types. Unlike many designs, nulling the input offset voltage does not degrade common-mode rejection ratio or input offset voltage drift. Low input voltage noise and current noise plus a low 1/f noise corner frequency allow these amplifiers to be used in a variety of low noise, wide-bandwidth applications.

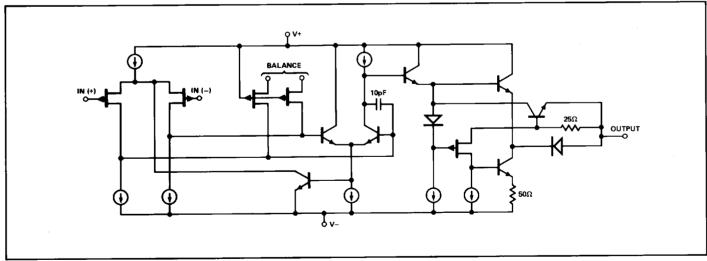
Dynamic specifications for the PM-155 include a slew rate of  $5V/\mu s$ , a 2.5MHz gain bandwidth product, and settling time to within  $\pm 0.01\%$  of final value in  $5.0\mu s$ . The PM-156 has a slew rate of  $12V/\mu s$  and a settling time of  $4.0\mu s$  to  $\pm 0.01\%$  of final value.

The PM-157 is a very fast decompensated device. This results in a  $45 \text{V}/\mu\text{s}$  slew rate, a 20MHz gain bandwidth product, and a settling time of  $4.0\mu\text{s}$ . Decompensation requires a minimum closed-loop gain of five because of stability considerations.

For improved performance, see the OP-15/OP-16/OP-17 data sheet. For duals, see the OP-215 data sheet.

#### SIMPLIFIED SCHEMATIC

Fast Settling to ±0.01% .....



#### **ABSOLUTE MAXIMUM RATINGS**

Supply Voltage PM-155A, PM-156A, PM-157A, PM-155, PM-156, PM-157,
PM-355A, PM-356A, PM-357A ±22V
Operating Temperature Range
PM-155A, PM-156A, PM-157A, PM-155, PM-156,
PM-15755° C to +125° C
PM-355A, PM-356A, PM-357A 0°C to +70°C
Maximum Junction Temperature (T <sub>i</sub> )
PM-155A, PM-156A, PM-157A, PM-155, PM-156,
PM-157+150°C
PM-355A, PM-356A, PM-357A+100°C
Differential Input Voltage
PM-155A, PM-156A, PM-157A, PM-155, PM-156, PM-157,
PM-355A, PM-356A, PM-357A ±40V
Input Voltage
PM-155A, PM-156A, PM-157A, PM-155, PM-156, PM-157,
PM-355A, PM-356A, PM-357A ±20V

Output Short-Circuit Duration	Indefinite
Storage Temperature Range	65°C to +150°C
Lead Temperature Range (Soldering, 60	

PACKAGE TYPE	Θ <sub>JA</sub> (NOTE 2)	Θ <sub>IC</sub>	UNITS
TO-99 (J)	150	18	*C/W
8-Pin Hermetic DIP (Z)	148	16	°C/W
20-Contact LCC (RC)	98	38	°C/W

#### NOTES:

- The absolute maximum negative input voltage is equal to the negative power supply voltage.
- Θ<sub>jA</sub> is specified for worst case mounting conditions, i.e., Θ<sub>jA</sub> is specified for device in socket for TO, CerDIP, and LCC packages.

**ELECTRICAL CHARACTERISTICS** at  $\pm 15 \text{V} \leq \text{V}_S \leq \pm 20 \text{V}$ ,  $-55^{\circ}\text{C} \leq \text{T}_A \leq +125^{\circ}\text{C}$  and  $\text{T}_{\text{HIGH}} = +125^{\circ}\text{C}$  for PM-155A, PM-156A and PM-157A,  $0^{\circ}\text{C} \leq \text{T}_A \leq +70^{\circ}\text{C}$  and  $\text{T}_{\text{HIGH}} = +70^{\circ}\text{C}$  for PM-355A, PM-356A and PM-357A, unless otherwise noted.

			PM-155A/ PM-156A/ PM-157A			PM-355A/ PM-356A/ PM-357A			
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Input Offset Voltage	Vos	$R_S = 50\Omega$	<u> </u>	1.4	2.5		1.2	2.3	mV_
Input Offset Voltage Drift	TCVos	$R_S = 50\Omega$		3	5	_	3	5	μV/° C
Change in Input Offset Drift with V <sub>OS</sub> Adjust	$\left(\frac{\Delta TCV_{OS}}{\Delta V_{OS}}\right)$	R <sub>S</sub> = 50Ω		0.5		_	0.5	_	μV/° C per mV
Input Offset Current	Ios	T <sub>j</sub> ≤ T <sub>HIGH</sub> (Note 1)	_	4.0	10		0.4	1.0	nA
Input Bias Current	I <sub>B</sub>	T <sub>j</sub> ≤ T <sub>HIGH</sub> (Note 1)		± 10	±25		±2	±5	nA
Large-Signal Voltage Gain	A <sub>vo</sub>	$V_S = \pm 15V$ , $V_O = \pm 10V$ , $R_L = 2k\Omega$	25	75	_	25	75		V/mV
Output Voltage Swing	v <sub>o</sub>	$V_S = \pm 15V, R_L = 10k\Omega$ $V_S = \pm 15V, R_L = 2k\Omega$	±12 ±10	±13 ±12	_ _	±12 ±10	±13 ±12		v
Input Voltage Range	IVR	V <sub>S</sub> = ± 15V	±10.4	+ 15.1 -12.0	_	±10.4	+15.1 -12.0	_	V
Common-Mode Rejection Ratio	CMRR	V <sub>CM</sub> = ±IVR	85	100	-	85	100	_	dB
Power Supply Rejection Ratio	PSRR	(Note 2)	_	10	57	_	10	57	μV/V

#### NOTES:

- 1. PMI has a bias current compensation circuit which gives improved bias current over the standard JFET input op amps.  $I_B$  and  $I_{OS}$  are measured at  $V_{CM} = 0$ .
- Power supply rejection ratio is measured for both supply magnitudes increasing or decreasing simultaneously, in accordance with common practice.

### **ELECTRICAL CHARACTERISTICS** at $\pm$ 15V $\leq$ V<sub>S</sub> $\leq$ $\pm$ 20V, T<sub>A</sub> = 25°C, unless otherwise noted.

			•	PM-155A/ PM-156A/ PM-157A		PM-355A/ PM-356A/ PM-357A				
PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Input Offset Voltage	Vos	R <sub>S</sub> = 50Ω		_	1	2		1	2	mV
Input Offset Current	los	T <sub>j</sub> = 25° C (Note 1)		_	3	10	_	3	10	pA
Input-Bias Current	l <sub>B</sub>	T <sub>j</sub> = 25° C (Note 1)		_	±30	±50	_	±30	±50	рΑ
Input Resistance	R <sub>IN</sub>			_	10 <sup>12</sup>	_	_	10 <sup>12</sup>	_	u
Large-Signal Voltage Gain	Avo	$V_S = \pm 15V, V_O = \pm 10V,$ $R_L = 2k\Omega$		50	200	_	50	200	_	V/mV
Supply Current	I <sub>SY</sub>	V <sub>8</sub> = ± 15V	PM-155 PM-156/PM-157	_	<b>2</b> 5	4 7		2 5	4 7	mA
Slew Rate	SR	$A_{VCL} = +1, V_S = \pm 15V$	PM-155 PM-156	3 10	5 12	<u>-</u>	3 10	5 12		V/μs
		$A_{VCL} = +5, V_S = \pm 15V$	PM-157	40	45	_	40	45	_	
Gain Bandwidth Product	GBW	$A_{VCL} = +1, V_S = \pm 15V$	PM-155 PM-156	_ 4.0	2.5 4.5	_	4.0	2.5 4.5	_	MHz
		$A_{VCL} = +5, V_S = \pm 15V$	PM-157	15	20		15	20		
Settling Time (to ±0.01%)	ts	V <sub>S</sub> = ±15V (Note 2)	PM-155 PM-156	_	5.0 4.0	_	_	4.0 1.5	_	μS
	•	$V_S = \pm 15V \text{ (Note 3)}$	PM-157	_	4.0	_	_	1.5	_	•
		$R_S = 100\Omega$ , $f = 100Hz$ $R_S = 100\Omega$ , $f = 1000Hz$	PM-155	_	25 20	_	_	25 20		
Input Noise Voltage	e <sub>n</sub>	$R_S = 100\Omega$ , $f = 100Hz$ $R_S = 100\Omega$ , $f = 1000Hz$	PM-156/PM-157		15 12	_	_	15 12	_	nV/√Hz
Input Noise Current	in	$f = 100Hz, V_S = \pm 15V$ $f = 1000Hz, V_S = \pm 15V$		_	0.01 0.01	_	_ _	0.01 0.01	_	pA∕√Hz
Input Capacitance	C <sub>IN</sub>				3	_	_	3	_	pF

#### NOTES:

- PMI has a bias current compensation circuit which gives improved bias current over the standard JFET input op amps. I<sub>B</sub> and I<sub>OS</sub> are measured at V<sub>CM</sub> = 0.
- Settling time is defined here for a unity gain inverter connection using 2kΩ
  resistors. It is the time required for the error voltage (the voltage at the
  inverting input pin on the amplifier) to settle to within 0.01% of its final
  value from the time a 10V step input is applied to the inverter. See settling
  time test circuit.
- 3. Settling time is defined here for a  $A_V = -5$  connection with  $R_F = 2k\Omega$ . It is the time required for the error voltage (the voltage at the inverting input pin on the amplifier) to settle to within 0.01% of its final value from the time a 2V step input is applied to the inverter. See settling time test circuit.

**ELECTRICAL CHARACTERISTICS** at  $\pm$  15V  $\leq$  V<sub>S</sub>  $\leq$   $\pm$  20V and  $-55^{\circ}$  C  $\leq$  T<sub>A</sub>  $\leq$  + 125 $^{\circ}$  C and T<sub>HIGH</sub> = + 125 $^{\circ}$  C for PM-155, PM-156 and PM-157, unless otherwise noted.

				PM-155 PM-156 PM-157		
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Input Offset Voltage	Vos	R <sub>S</sub> = 50Ω	_	4	7	mV
Input_Offset Voltage Drift	TCVos	R <sub>S</sub> = 50Ω	_	5	_	μV/° C
Change In Input Offset Drift With VOS Adjust.	$\left(\frac{\Delta TCV_{OS}}{\Delta V_{OS}}\right)$	R <sub>S</sub> = 50Ω	्र प	0.5	_	μV/°C per mV
Input Offset Current	Ios	T <sub>j</sub> ≤ T <sub>HIGH</sub> (Note 1)	_	8	20	nA
Input Bias Current	IB	T <sub>j</sub> ≤ T <sub>HIGH</sub> (Note 1)	_	±2	±50	nA
Large-Signal Voltage Gain	Avo	$V_S = \pm 15V$ , $V_O = \pm 10V$ $R_L = 2k\Omega$	25	75	_	V/mV
Output Voltage Swing	v <sub>o</sub>	$V_S = \pm 15V$ , $R_L = 10k\Omega$ $V_S = \pm 15V$ , $R_L = 2k\Omega$	±12 ±10	± 13 ± 12	_	V
Input Voltage Range	IVR	V <sub>S</sub> = ± 15V	±10.4	+ 15.1 -12.0	_	٧
Common-Mode Rejection Ratio	CMRR	V <sub>CM</sub> = ± IVR	85	100	_	dB
Power Supply Rejection Ratio	PSRR	(Note 2)	_	10	57	μV/V

#### NOTES:

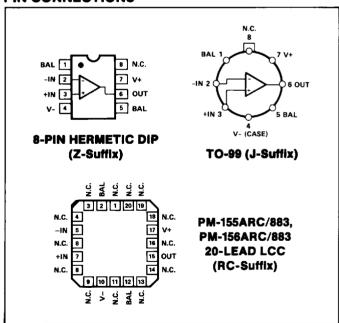
Power supply rejection ratio is measured for both supply magnitudes increasing or decreasing simultaneously, in accordance with common practice.

#### **ORDERING INFORMATION†**

		PACKAGE		
T <sub>A</sub> = 25° C V <sub>OS</sub> MAX (mV)	TO-99 8-PIN	8-PIN HERMETIC DIP	LCC	OPERATING TEMPERATURE RANGE
	PM155AJ*	PM155AZ/883	PM155ARC/883	
2.0	PM156AJ*	PM156AZ*	PM156ARC/883	MIL
	PM157AJ/883	PM157AZ*	_	
	PM355AJ	PM355AZ	_	
2.0	PM356AJ	PM356AZ	_	COM
	PM357AJ	PM357AZ	_	
	PM155J*	PM155Z*	_	
5.0	PM156J*	PM156Z*	_	MIL
	PM157J*	PM157Z*	_	

For devices processed in total compliance to MIL-STD-883, add /883 after part number. Consult factory for 883 data sheet.

#### **PIN CONNECTIONS**



<sup>1.</sup> PMI has a bias current compensation circuit which gives improved bias current over the standard JFET input op amps.  $I_B$  and  $I_{OS}$  are measured at  $V_{CM} = 0$ ,  $T_i = +125^{\circ}$  C.

Burn-in is available on commercial and industrial temperature range parts in CerDIP, plastic DIP, and TO-can packages.

**ELECTRICAL CHARACTERISTICS** at  $T_A = +25^{\circ}$  C,  $\pm 15$  V  $\leq$  V<sub>S</sub>  $\leq \pm 20$  V for PM-155, PM-156 and PM-157, unless otherwise noted.

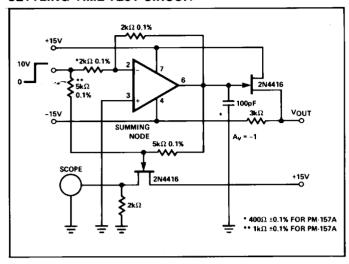
					PM-159 PM-150 PM-157	В	
PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Input Offset Voltage	Vos	R <sub>S</sub> = 50Ω		_	3	5	mV
Input Offset Current	los	T <sub>j</sub> = 25° C (Note 1)		_	3	20	pA
Input Bias Current	I <sub>B</sub>	T <sub>j</sub> = 25° C (Note 1)		_	±30	±100	pA
Input Resistance	R <sub>IN</sub>			_	10 <sup>12</sup>	_	U
Large-Signal Voltage Gain	A <sub>VO</sub>	$V_S = \pm 15 V, V_O = \pm 10 V,$ $R_L = 2k\Omega$		50	200	_	V/mV
Supply Current	I <sub>SY</sub>	V <sub>S</sub> = ± 15V	PM-155 PM-156/PM-157	=	2 5	4 7	mA
Slew Rate	SR	$A_{VCL} = +1, V_8 = \pm 15V$	PM-155 PM-156	_ 7.5	5 12	_	V/μs
		$A_{VCL} = +5, V_S = \pm 15V$	PM-157	30	40	<del></del> .	
Gain Bandwidth Product	GBW	$A_{VCL} = +1, V_S = \pm 15V$	PM-155 PM-156	_	2.5. 5	_	MHz
		$A_{VCL} = +5, V_S = \pm 15V$	PM-157	_	20	_	
Settling Time (to ±0.01%)	ts	V <sub>S</sub> = ±15V (Note 2)	PM-155 PM-156	_	5 4	_	μ8
•	Ū	$V_8 = \pm 15V \text{ (Note 3)}$	PM-157	_	4	_	<b>,</b>
1A-1		$R_S = 100\Omega$ , $f = 100Hz$ $R_S = 100\Omega$ , $f = 1000Hz$	PM-155	_	25 20	_	
Input Noise Voltage	e <sub>n</sub>	$R_S = 100\Omega$ , $f = 100Hz$ $R_S = 100\Omega$ , $f = 1000Hz$	PM-156/PM-157	_	15 12	_	nV/√Hz
Input Noise Current	in	$f = 100Hz, V_S = \pm 15V$ $f = 1000Hz, V_S = \pm 15V$		_	0.01	_	pA√√Hz
Input Capacitance	C <sub>IN</sub>			_	3	_	pF

#### NOTES:

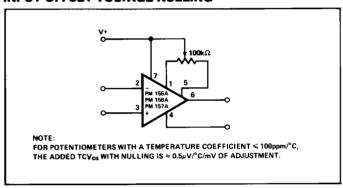
- 1. PMI has a bias current compensation circuit which gives improved bias current over the standard JFET input op amps.  $I_B$  and  $I_{OS}$  are measured at  $V_{CM} = 0$ .
- Settling time is defined here for a unity gain inverter connection using 2kΩ
  resistors. It is the time required for the error voltage (the voltage at the
  inverting input pin on the amplifier) to settle to within 0.01% of its final
  value from the time a 10V step input is applied to the inverter. See settling
  time test circuit.
- 3. Settling time is defined here for a  $A_V=-5$  connection with  $R_F=2k\Omega$ . It is the time required for the error voltage (the voltage at the inverting input pin on the amplifier) to settle to within 0.01% of its final value from the time a 2V step input is applied to the inverter. See settling time test circuit.

#### **BASIC CONNECTIONS**

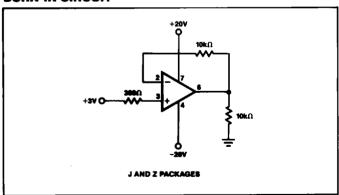
#### **SETTLING-TIME TEST CIRCUIT**



#### INPUT OFFSET VOLTAGE NULLING



#### **BURN-IN CIRCUIT**



#### **APPLICATIONS INFORMATION**

#### **INPUT VOLTAGE CONSIDERATIONS**

The PM series JFET input stages can accommodate large input differential voltages without external clamping as long as neither input exceeds the negative power supply. An input voltage which is more negative than V- can result in a destroyed unit.

If both inputs exceed the negative common-mode voltage limit, the amplifier will be forced to a high positive output. If only one input exceeds the negative common-mode voltage limit, a phase reversal takes place forcing the output to the corresponding high or low state. In either of the above conditions, normal operation will return when both inputs are returned to within the specified common-mode voltage range.

Exceeding the positive common-mode limit on a single input will not change the phase of the output. However, if both inputs exceed the limit, the output of the amplifier will be forced to a high state.

#### **POWER SUPPLY CONSIDERATIONS**

Power supply polarity reversal can result in a destroyed unit.

#### **DYNAMIC OPERATING CONSIDERATIONS**

As with most amplifiers, care should be taken with lead dress, component placement, and supply decoupling in order to ensure stability. For example, resistors from the output to an input should be placed with the body close to the input. This minimizes "pick-up" and increases the frequency of the feedback pole by minimizing the capacitance from input to ground.

A feedback pole is created when the feedback around any amplifier is resistive. The parallel resistance and capacitance from the input of the device to AC ground sets the frequency of the pole. In many instances, the frequency of this pole is much greater than the expected 3dB frequency of the closed-loop gain. Consequently, the pole has negligible effect on stability margin. However, if the feedback pole is less than approximately six times the expected 3dB frequency, a lead capacitor should be placed from the output to the inverting input of the op amp. The capacitor value should be such that the RC time constant of the capacitor and feedback resistor is greater than, or equal to, the original feedback-pole time constant.